

### **DESCRIPTION**

The A4715 is a Dual Wide-Bandwidth, fast single-pole double-throw (SPDT) CMOS switch featuring an On-Resistance of 2.7 ohm at V<sub>DD</sub>=5.0V and wide power supply range from 1.8V to 5.5V. It can be used as an analog switch or as a low-delay bus switch.

The 300MHz high bandwidth performance supports the high frequency application.

Break-before-make function for both parts eliminates signal disruption during switching from preventing both switches being enabled simultaneously.

The A4715 is available in MSOP10 Package

#### ORDERING INFORMATION

Package Type	Part Number				
MSOP10	MS10	A4715MS10R			
SPQ: 3,000pcs/Reel	MSTU	A4715MS10VR			
Note	V: Halogen free package				
Note	R: Tape & Reel				
AiT provides all RoHS products,					

### **FEATURES**

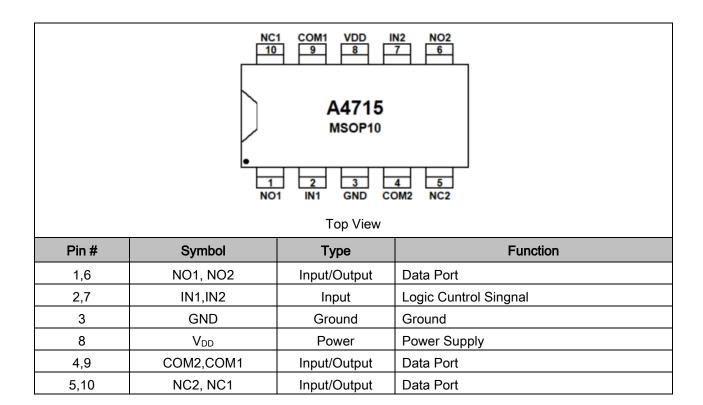
- Wide Power Supply Range: 1.8V to 5.5V
- High Bandwidth: 300MHz
- High Off-Isolation:
   84dB at 1MHz
   51dB at 10MHz
- Low Crosstalk: 80dB at 1MHz
- On-Resistance: 2.7Ω(typ) at 5.0V
- Fast Switching Time
   ton = 12.0ns; toff = 5.0ns
- TTL/CMOS Compatible
- Break-Before-Make Switching
- Rail-to-Rail Signal Range
- Operation Temperature Range:
   -40°C to 85°C
- Available in MSOP10 Package

### **APPLICATION**

- Wireless Handsets
- MP3 Players
- Portable Electronic Devices
- Relay Replacement
- PDAs
- Audio & Video Signal Routing
- PCMCIA Cards
- Computer Peripherals
- Modems

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## PIN DESCRIPTION



## **FUNCTION TABLE**

IN <sub>X</sub>	Function
0	NC <sub>X</sub> Connected to COM <sub>X</sub>
1	NO <sub>x</sub> Connected to COM <sub>x</sub>

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## **ABSOLUTE MAXIMUM RATINGS**

V <sub>DD</sub> , DC Supply Voltage	-0.3∨ ~ 6∨
V <sub>NO</sub> / V <sub>NC</sub> / V <sub>COM</sub> , DC Switch Voltage	-0.3V ~ V <sub>SUP</sub> +0.3V
V <sub>IN</sub> , DC Input Voltage	-0.3V ~ V <sub>SUP</sub> +0.3V
I <sub>(NO/NC/COM)</sub> , Continuous Current	-200mA ~ +200mA
IPEAK(NO/NC/COM), Peak CurrentNOTE1	-300mA ~ +300mA
T <sub>A</sub> , Operating Temperature Range	-40°C ~ 85°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE1: Pulsed at 1ms, 50% duty circle

NOTE2: Stress beyond above listed "Absolute Maximum Ratings" may lead permanent damage to the device.

These are stress ratings only and operations of the device at these or any other conditions beyond those indicated in the operational sections of the specifications are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

NOTE3: Control input( $V_{\text{IN}}$ ) must be held HIGH or LOW, and mustn't be floated.

## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
DC Supply Voltage	$V_{DD}$		1.8	-	5.5	V
Switch Input Voltage	Vs		0	-	$V_{DD}$	V
Control Input Voltage	V <sub>IN</sub>		0	-	$V_{DD}$	V
Operation Temperature	TA		-40	_	+85	°C

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# DC ELECTRICAL CHARACTERISTICS @ +2.7V Supply

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Parameter	Symbol	Conditions	Min.	Typ. NOTE1	Max.	Unit
Analog Switch						
Analog Signal Range	V <sub>NO</sub> , V <sub>NC</sub> , V <sub>COM</sub>		0	-	$V_{DD}$	V
NO On-Resistance	Ron(NO)	$V_{DD} = 2.7V; I_{COM} = -10mA;$ $V_{NO} = 1.5V$	-	6.5	1	Ω
NC On-Resistance	Ron(NC)	V <sub>DD</sub> = 2.7V; I <sub>COM</sub> =-10mA ; V <sub>NC</sub> =1.5V	-	6.5	-	Ω
NO On-Resistance Flatness <sup>NOTE2</sup>	R <sub>FLAT(NO)</sub>	$V_{DD} = 2.7V; I_{COM} = -10mA;$ $V_{NO} = 1.5V$	-	2.3	1	Ω
NC On-Resistance Flatnes NOTE2	RFLAT(NC)	$V_{DD} = 2.7V; I_{COM} = -10mA;$ $V_{NC} = 1.5V$	-	2.3	1	Ω
On-Resistance Match Between Channels <sup>NOTE3</sup>	ΔRon	$V_{DD} = 2.7V; I_{COM} = -10mA;$ $V_{NO} / V_{NC} = 1.5V$	-	0.15	1	Ω
NO or NC Off Leakage Current	loff (NO) or loff (NC)	$V_{DD} = 3.6V;$ $V_{NO} \text{ or } V_{NC} = 3V, 0.3V;$ $V_{COM} = 0.3V, 3V$	-	0.01	1	uA
COM On Leakage Current	Іол(сом)	$V_{DD} = 3.6V;$ $V_{NO} \text{ or } V_{NC} = 3.3V, 0.3V;$ $V_{COM} = 0.3V, 3.3 \text{ V or floating}$	-	0.01	1	uA
Digital I/O	•					
Input Voltage High	ViH	Minimum High Level Input Voltage	1	-	-	V
Input Voltage Low	V <sub>IL</sub>	Maximum Low Level Input 0.5		0.5	V	
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = 0V \text{ or } V_{DD}$	-	0.01	1	uA

NOTE1: Typical characteristics are at +3V supply and +25°C

NOTE2: Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal ranges.

NOTE3:  $\Delta R_{ON}$ =  $R_{ON(MAX)}$  -  $R_{ON(MIN)}$ , between NO and NC .

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# DYNAMIC CHARACTERISTICS @ +2.7V Supply

		Conditions		Guaranteed Limit			
Parameter	Symbol			Min.	Typ.	Max.	Unit
AC ELECTRICAL CHARACTERISTICS							
Turn-On Time	ton	$V_{DD} = 2.7V; V_{NO} \text{ or } V_{NC} = 1.5V,$ $R_L = 300\Omega; C_L = 35pF,$ $V_{IH} = 1.5V, V_{IL} = 0V$		-	17.0	-	ns
Turn-Off Time	toff		$V_{DD} = 2.7V$ ; $V_{NO}$ or $V_{NC} = 1.5V$ , $R_L = 300\Omega$ ; $C_L = 35pF$ ,		9.0	-	ns
Break-Before-Make Time	<b>t</b> ввм	$V_{DD} = 2.7V$ ; $V_{NO}$ or $V_{NC} = 1.5V$ , $R_L = 300\Omega$ ; $C_L = 35pF$		-	15.0	-	ns
NC OFF Capacitance	Coff(NC)	f = 1MHz		-	5.5	-	pF
NO OFF Capacitance	Coff(NO)	f = 1MHz		-	5.5	-	pF
NC ON Capacitance	C <sub>ON(NC</sub> )	f = 1MHz		-	15.5	-	pF
NO ON Capacitance	C <sub>ON(NO)</sub>	f = 1MHz		-	15.5	-	pF
ADDITIONAL APPLICATION	N CHARAC	TERISTICS					
3dB Bandwidth	f <sub>3dB</sub>	Signal = 0dBm, $R_L$ = 50 $\Omega$ , $C_L$ = 5pF		-	300	-	MHz
Off IsolationNOTE2	VIso	$R_L = 50\Omega$ ,	f = 1MHz	-	-84	-	dB
On isolation	V ISO	C <sub>L</sub> = 5pF, Signal = 0dBm	f=10MHz	-	-51	-	dB
Crosstalk	XTALK	$R_L = 50\Omega$ ,	f = 1MHz	-	-80	-	dB
Ologgiain	ATALIX	C <sub>L</sub> = 5pF	f = 10MHz	-	-78	-	dB
Supply		T			Т		T
Power Supply Range	$V_{DD}$	10700		1.8	-	5.5	V

NOTE1: Typical characteristics are at +3V supply and 25°C NOTE2: Off Channel Isolation =  $20log_{10} [(V_{NOINC})/V_{COM}]$ 

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# DC ELECTRICAL CHARACTERISTICS @ +5.0V Supply

			Gua			
Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Analog Switch						
Analog Signal Range	V <sub>NO</sub> , V <sub>NC</sub> , V <sub>COM</sub>		0	-	$V_{DD}$	V
NO On-Resistance	Ron(NO)	$V_{DD} = 5.0V; I_{COM} = -10mA;$ $V_{NO} = 3.5V$	-	2.7	-	Ω
NC On-Resistance	Ron(NC)	V <sub>DD</sub> = 5.0V; I <sub>COM</sub> =-10mA; V <sub>NC</sub> =3.5V	_	2.7	-	Ω
NO On-Resistance Flatness <sup>NOTE2</sup>	R <sub>FLAT(NO)</sub>	$V_{DD} = 5.0V; I_{COM} = -10mA;$ $V_{NO} = 3.5V$	_	0.8	-	Ω
NC On-Resistance Flatnes NOTE2	RFLAT(NC)	V <sub>DD</sub> = 5.0V; I <sub>COM</sub> =-10mA; V <sub>NC</sub> =3.5V	-	0.8	-	Ω
On-Resistance Match Between Channels <sup>NOTE3</sup>	ΔRon	V <sub>DD</sub> = 5.0V; I <sub>COM</sub> =-10mA ; V <sub>NO</sub> /V <sub>NC</sub> =3.5V	-	0.15	-	Ω
NO or NC Off Leakage Current	loff (NO) <b>O</b> r loff (NC)	$V_{DD} = 5.5V;$ $V_{NO} \text{ or } V_{NC} = 4.5V, 1.0V;$ $V_{COM} = 1.0V, 4.5V$	-	0.01	1	uA
COM On Leakage Current	Ion(B)	$V_{DD} = 5.5V;$ $V_{NO} \text{ or } V_{NC} = 4.5V, 1.0V;$ $V_{COM} = 1.0V, 4.5 \text{ V or floating}$	-	0.01	1	uA
Digital I/O						
Input Voltage High	ViH	Minimum High Level Input Voltage	1	-	-	V
Input Voltage Low	V <sub>IL</sub>	Maximum Low Level Input - 0.5		V		
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 0V or V <sub>DD</sub>	-	0.01	1	uA

NOTE1: Typical characteristics are at +5.0V supply and +25°C

NOTE2: Flatness is defined as the difference between the maximum and minimum value of on resistance as measured over the specified analog signal ranges.

NOTE3:  $\Delta R_{ON}$ =  $R_{ON(MAX)}$  -  $R_{ON(MIN)}$ , between NO and NC .

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# DYNAMIC CHARACTERISTICS @ +5.0V Supply

			Gua				
Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
AC ELECTRICAL CHARAC							
Turn-On Time	ton	$V_{DD}$ = 5.0V; $V_{NO}$ or $V_{NC}$ = 3.0V, $R_L$ = 300 $\Omega$ ; $C_L$ = 35pF, $V_{IH}$ =1.5V, $V_{IL}$ =0V		-	12.0	-	ns
Turn-Off Time	toff		$V_{DD} = 5.0V$ ; $V_{NO}$ or $V_{NC} = 3.5V$ , $R_L = 300\Omega$ ; $C_L = 35pF$ ,		5.0	ı	ns
Break-Before-Make Time	tввм	$V_{DD} = 5.0V$ ; $V_{NO}$ or $V_{NC} = 3.5V$ , $R_L = 300\Omega$ ; $C_L = 35pF$		-	8.5	-	ns
NC OFF Capacitance	Coff(NC)	f = 1MHz		-	5.5	-	pF
NO OFF Capacitance	Coff(NO)	f = 1MHz		1	5.5	1	pF
NC ON Capacitance	C <sub>ON(NC</sub> )	f = 1MHz		-	15.5	1	pF
NO ON Capacitance	C <sub>ON(NO)</sub>	f = 1MHz		-	15.5	-	pF
ADDITIONAL APPLICATION	N CHARAC	TERISTICS					
3dB Bandwidth	f <sub>3dB</sub>	Signal = 0dBm, $R_L$ = 50 $\Omega$ , $C_L$ = 5pF		-	300	-	MHz
Off Isolation <sup>NOTE2</sup>	V <sub>Iso</sub>	$R_L = 50\Omega$ ,	f = 1MHz	-	-84	-	dB
On isolation	V 150	o C∟ = 5pF, Signal = 0dBm	f=10MHz	-	-51	-	dB
Crosstalk	XTALK	$R_L = 50\Omega$ ,	f = 1MHz	-	-78	-	dB
	MIALI	C <sub>L</sub> = 5pF	f = 10MHz	-	-80	-	dB
Supply		T					
Power Supply Range	$V_{DD}$			1.8	-	5.5	V

NOTE1: Typical characteristics are at +5.0V supply and 25°C

NOTE2: Off Channel Isolation = 20log<sub>10</sub> [(V<sub>NO\NC</sub>)/V<sub>COM</sub>]

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# **TEST SETUP CIRCUITS**

Figure 1. Test Circuit for On Resister

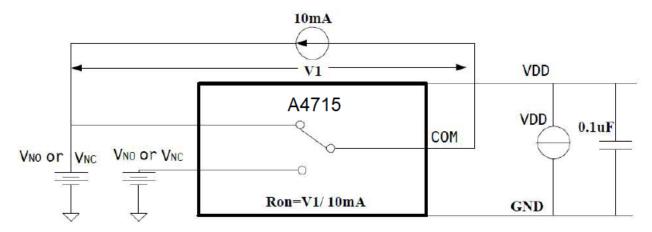


Figure 2. Test Circuit for Bandwidth

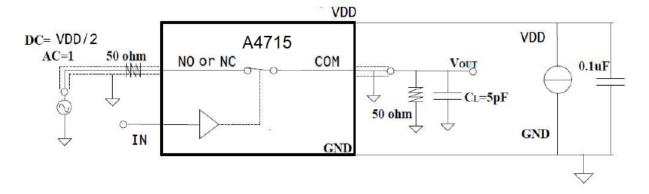
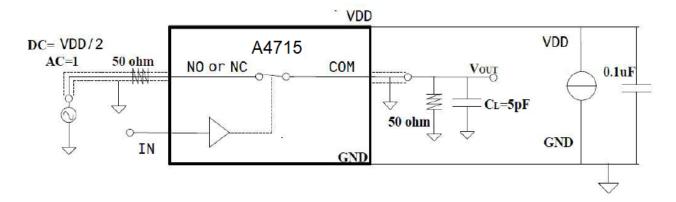
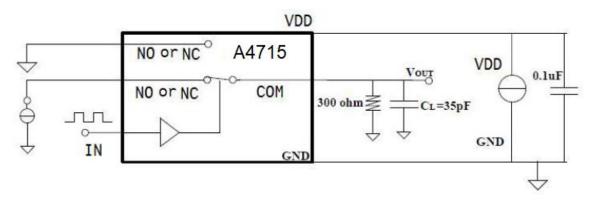


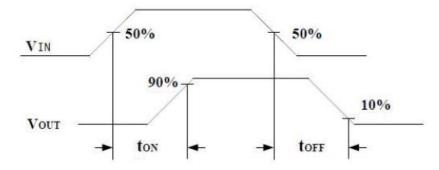
Figure 3. Test Circuit for Off Isolation



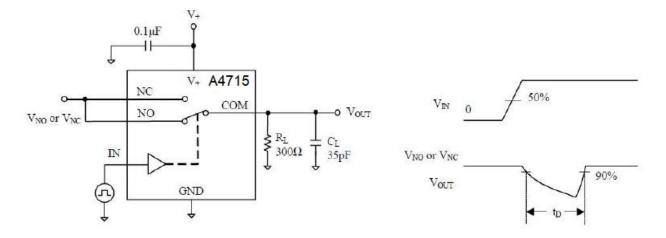
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### Test Circuit 4. Test Circuit for Switch Times



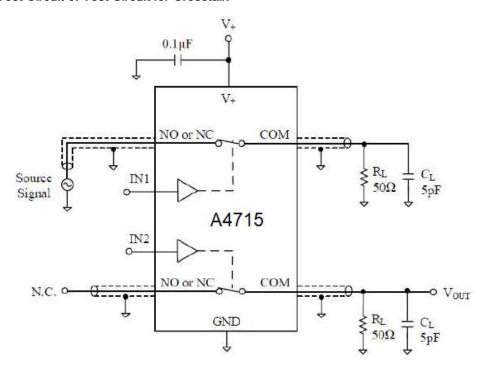


Test Circuit 5. Test Circuit for Break-Before-Make Time Delay, t<sub>D</sub>



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### Test Circuit 6. Test Circuit for Crosstalk

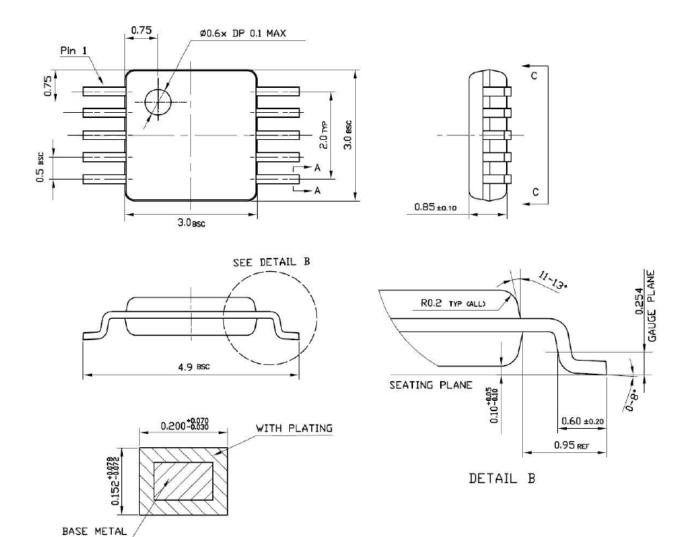


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# PACKAGE INFORMATION

Dimension in MSOP10 Package (Unit: mm)

SECTION A-A



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## IMPORTANT NOTICE

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